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Correction: Electronic and transport properties of Li-doped NiO epitaxial thin films

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Correction for 'Electronic and transport properties of Li-doped NiO epitaxial thin films' by J. Y. Zhang *et al.*, *J. Mater. Chem. C*, 2018, **6**, 2275–2282.

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The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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